## NSN 5961-00-068-8551

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-068-8551 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.125 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 6.0 forward voltage, average **Current Rating Per Characteristic:** 500.00 milliamperes base current, dc and 150.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 250.0 milliwatts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 07187-2579511 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No